Hole-LO phonon interaction in InAs/GaAs quantum dots

VANESSA PREISLER, SOPHIE HAMEAU, ROBSON FERREIRA, LOUIS-ANNE DE VAULCHIER, YVES GULDNER, Ecole Normale Supérieure, ARISTIDE LEMAÎTRE, Laboratoire de Photonique et de Nanostructures — Various experimental and theoretical works demonstrate that electrons confined in quantum dots are strongly coupled to the longitudinal optical (LO) vibrations of the underlying semiconductor lattice [?]. This leads to the formation of the so-called quantum dot polaron, which are the true excitations of a charged dot. The interaction between holes confined in quantum dots and LO phonons has not, until now, been explored. We present a study of holes confined in InAs/GaAs quantum dots doped with Be. The interaction between the holes in the dots and the LO phonons of the lattice is studied experimentally by spectroscopy in the FIR (50 – 700 cm$^{-1}$) energy range and under the influence of a magnetic field (0-15T). We observe several resonances in magneto-transmission around 200 cm$^{-1}$. In order to interpret our experimental results, we calculate the coupling between the hole-phonon states, using the Fröhlich Hamiltonian. The resulting polaron states we find are in good agreement with our experimental results.

References